Excitons in periodic potentials

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The energy band structure of excitons is studied in periodic potentials produced by the short-range interaction between the exciton and electrons of Wigner lattices. Treating the exciton as a pointlike dipole that interacts with the periodic potential, we can solve a simple one-body problem that provides valuable information on excitons in many-body problem settings. By employing group theory, we identify the excitonic energy bands that can couple to light and then quantify their energy shifts in response to a change in the period of the potential. This approach allows us to emulate the response of optically active exciton and trion states to a change in electron density. In agreement with experimental results, the exciton (trion) state shows a relatively strong (weak) energy shift when the electron density increases. This behavior stems from the difficulty of exciton states to remain extended, whereas the trion state remains largely the same as long as its radius is smaller than the average distance between resident electrons. We identify an important relation between the energy blueshift of bright excitons and the presence of a Wigner crystal, where the blueshift magnitude is proportionate to the symmetry of the electron lattice.

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Excitons in semiconductors allow us to explore intriguing many-body phenomena in condensed matter physics [1–3]. Through changes in energy, fine structure, and oscillator strength of excitons in response to electrostatic gating or magnetic fields, we can learn about Fermi-edge singularities [4,5], composite states [6,7], proximity effects [8,9], Fermi polarons [10,11], Wigner crystals [12,13], fractional filling of moiré valleys [14,15], as well as dynamical screening and exchange-correlation interactions [16,17]. Many of these problems are hard to tackle from a theoretical standpoint since it is impossible to solve the many-body wave function of the exciton and all interacting electrons. Instead, approximated solutions usually treat the excitonic state as a quasiparticle that is dressed by the interacting electrons [18-28]. That is, the exciton creation polarizes the electron gas, and the resulting displacement of electrons modifies the exciton wave function. An important question that arises is whether experimental results can be explained without the polarization of the electron

The motivation for asking this question is that experiments in electrostatically doped semiconductors are often conducted in the limit $r_x \ll r_s$, where r_x is the exciton radius and r_s is the average distance between two nearby conduction-band electrons [29–35]. Given that electrons are far more influenced by the long-range Coulomb interaction between them than by the short-range interaction with the exciton, the displacement of electrons in this system can be energetically costly. We argue in this Letter that as long as $r_x \ll r_s$, the excitonic absorption spectrum can be well explained by assuming that electrons are "frozen" at fixed positions. The short-range interaction between the exciton and electron is replaced by a static potential, allowing us to readily solve such an exciton problem.

There are two ways to study the interaction between the exciton and the potential produced by a frozen landscape of electrons in the host material. One approach is to assume that electrons are distributed at random positions, and then study the exciton wave function through its phase shift when the charge density increases. We employ this method in a companion paper [36]. The second approach is to assume that the electrons are ordered, as in the case of a Wigner crystal [37]. One can then study the dependence of the exciton wave function on electron density through the ensuing change in the lattice constant of the electrons crystal. We take the second approach in this Letter, allowing us to calculate the exciton energies by standard band theory [38,39]. We identify an important relation between the energy blueshift of bright excitons and the Wigner crystal symmetry. This relation is further analyzed in Ref. [36], showing that the energy blueshift gradually increases as electrons continuously acquire order (starting from a random distribution of electrons in the monolayer that is gradually transitioning to an electron Wigner crystal). Hereafter, the crystal, lattice, and Brillouin zone refer to the Wigner electron crystal and not the semiconductor atomic crystal.

Our study focuses on two-dimensional (2D) crystals. Given that $r_x \ll r_s$, where r_s is now the lattice constant, we neglect the internal relative motion of the electron and hole components in the exciton and treat the small exciton complex as one body with translational mass M. Furthermore, the lattice sites are assumed to be made of electrons with different quantum numbers (spin and/or valley) than those of the electron in the exciton [40,41]. This distinguishability not only allows

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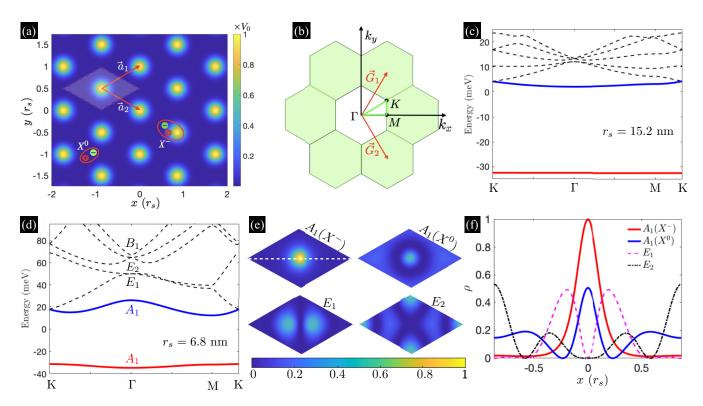


FIG. 1. (a) Illustration of the short-range potential profile experienced by an exciton in a triangular electron lattice. The unit cell and basis vectors $\mathbf{a}_{1,2}$ are highlighted, where the distance between two neighboring sites is $r_s = |\mathbf{a}_{1,2}|$. An electron-hole pair propagating in this lattice can form bound or unbound states with the lattice $(X^- \text{ or } X^0)$, corresponding to trion or exciton energy bands, respectively. (b) The first (white) and second (green) Brillouin zones of the triangular lattice, along with the reciprocal-lattice basis vectors $\mathbf{G}_{1,2} = 2\pi (1/\sqrt{3}, \pm 1)/r_s$ and high-symmetry points Γ, M, and K. (c) and (d) Exciton band structures along axes between high-symmetry points, shown for lattice constants $r_s = 15.2$ and 6.8 nm, or equivalently, electron densities $n = 5 \times 10^{11}$ cm⁻² and $n = 2.5 \times 10^{12}$ cm⁻², respectively. The energy bands in (d) are labeled with their Γ-point IRs (Table I). (e) Square amplitude color maps of the Γ-point wave functions in the unit cell, where (f) shows these results along the axis marked by the dashed white line in (e).

the exciton to bind to the lattice and form a trionlike state, but it will be shown to introduce a strong energy blueshift of excitonlike states. The indistinguishable case is studied in the companion paper [36]. Without loss of generality, we consider a periodic Gaussian function to describe the short-range potential exerted on the exciton by the lattice [42],

$$V(\mathbf{r}) = \sum_{n_1, n_2} V_0 \exp(-|\mathbf{r} - n_1 \mathbf{a}_1 - n_2 \mathbf{a}_2|^2 / w^2).$$
 (1)

r is the center-of-mass coordinate of the exciton. $n_{1,2}$ are integers, $\mathbf{a}_{1,2}$ are the lattice basis vectors, w is the potential range, and V_0 is its amplitude. Figures 1(a) and 1(b) show a density plot of the potential in a triangular lattice and the corresponding Brillouin zone, respectively.

We employ the pseudopotential method to calculate the exciton band structure [43]. The Bloch wave function,

$$\psi_{\mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k}\cdot\mathbf{r}}u_{\mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k}\cdot\mathbf{r}}\sum_{\mathbf{G}}u_{\mathbf{k}}(\mathbf{G})e^{i\mathbf{G}\cdot\mathbf{r}},$$
 (2)

is written as a modulated periodic function $u_k(\mathbf{r})$, expanded as a sum over reciprocal lattice vectors \mathbf{G} . The Fourier components $u_k(\mathbf{G})$ and exciton eigenenergies E_k are obtained from

the matrix equation

$$\sum_{\mathbf{G}'} H_{\mathbf{G}\mathbf{G}'}(\mathbf{k}) u_{\mathbf{k}}(\mathbf{G}') = E_{\mathbf{k}} u_{\mathbf{k}}(\mathbf{G}), \tag{3}$$

where the Hamiltonian in reciprocal space reads

$$H_{\mathbf{G}\mathbf{G}'}(\mathbf{k}) = \frac{\hbar^2 (\mathbf{k} + \mathbf{G})^2}{2M} \delta_{\mathbf{G},\mathbf{G}'} + V(\mathbf{G} - \mathbf{G}'). \tag{4}$$

 $V(\mathbf{G} - \mathbf{G}')$ is the Fourier transform of the crystal potential per unit cell [44].

Figures 1(c) and 1(d) show results of the exciton band structure for two lattice constants, r_s , related through $nr_s^2 = 2/\sqrt{3}$ to the electron density in a triangular Wigner crystal. The crystal potential parameters are w = 1 nm and $V_0 = -170$ meV, and the exciton translation mass is $M = 0.65m_0$, where m_0 is the free-electron mass. These are the only three material-specific parameters, and here we chose them to mimic the behavior in transition-metal dichalcogenide (TMD) monolayers [45], where w is comparable to the exciton radius, V_0 is chosen to yield a trionlike band (explained below), and M denotes the center-of-mass rather than reduced mass of the exciton. The zero-energy level in our calculations is the exciton resonance energy in the limit $r_s \to \infty$, corresponding to an intrinsic semiconductor $(n \to 0)$.

TABLE I. Character table of point group D_6 . The symmetry operators include the identity operation E, $\pm 2\pi/\ell$ rotations around the z axis $[C_\ell(z)]$, and π rotations around axes that connect nearest-neighbor sites of the triangular lattice (C_2') , and next-nearest-neighbor sites (C_2'') .

$\overline{D_6}$	Е	$2C_{6}(z)$	$2C_3(z)$	$C_2(z)$	$3C'_{2}$	$3C_{2}''$	Linear functions
$\overline{A_1}$	+1	+1	+1	+1	+1	+1	
A_2	+1	+1	+1	+1	-1	-1	z
B_1	+1	-1	+1	-1	+1	-1	
B_2	+1	-1	+1	-1	-1	+1	
E_1	+2	+1	-1	-2	0	0	x, y
E_2	+2	-1	-1	+2	0	0	

The result of having one site per unit cell [Fig. 1(a)] is that only one band has negative energies, as shown in Figs. 1(c) and 1(d). The negative-energy band mimics the trion state, which is tightly bound to a lattice site, as shown in Figs. 1(e) and 1(f) for the square amplitude of the lowest-energy wave function at the Γ point (X^-). The energy of the trionlike band is ~ -32 meV in both Figs. 1(c) and 1(d), implying that this energy level is weakly dependent on lattice constant (electron density) and mostly governed by the trapping amplitude of the potential, V_0 . This behavior persists as long as $w \sim r_x \ll r_s$, leading to strong localization of trionlike states at the lattice sites. The nearly flat nature of this energy band implies a very large effective mass, or equivalently, suppressed hopping between neighboring lattice sites.

The positive-energy bands in Figs. 1(c) and 1(d) describe states in which the exciton tends to stay away from lattice sites (i.e., not bound to the crystal). Figures 1(e) and 1(f) show that the Γ -point wave functions become more extended across the unit cell as the energy of the state increases. To check which of the states can strongly couple to light, we look for wave functions that retain the 1s character of the envelope function of the bright exciton [38]. Before embarking on the symmetry analysis, we note that focusing on the Γ -point wave functions is justified when the lattice constant r_s is much smaller than the photon wavelength needed to create the bright exciton of the semiconductor (λ_x). Put differently, the exciton momentum following light excitation is much smaller than the width of the Brillouin zone, $h/\lambda_x \ll 2\pi/r_s$.

Table I shows the character table of point group D_6 , corresponding to the Γ point of the 2D triangular lattice, where the z axis is along the out-of-plane direction. Among the seven lowest-energy states of the Γ point that we show in Figs. 1(c) and 1(d), only the lowest two transform as the identity irreducible representation (IR) A_1 . The transformation properties of A_1 describe the envelope functions of the ground-state trion or exciton (1s), whose coupling to light is strongest. Of the remaining Γ -point states that are shown in Figs. 1(c)-1(f), those that transform as E_1 can turn valuable in experiment. The doubly degenerate IR E_1 transforms as an in-plane vector (x and y). As such, the selection rule $A_1 \times E_1 = E_1$ mandates that the dipole transition between E_1 and A_1 states does not vanish, $\langle A_1 | \mathbf{p} | E_1 \rangle \neq 0$, where the momentum operator \mathbf{p} also transforms as an in-plane vector (i.e., represented by E_1). As we show next, the consequences of this property can be used to test if the electrons are ordered in a Wigner lattice.

Consider a photoexcited semiconductor with trions or excitons in their ground state (1s). The center-of-mass envelope functions of these excitonic complexes are described by the two aforementioned A_1 states if the electrons in the semiconductor are ordered in a Wigner lattice. If the semiconductor is further excited by a second light source with far-infrared photons, the absorption of these photons is greatly enhanced when their energy matches the energy gap between A_1 and E_1 states, $E_{E_1} - E_{A_1}$. To verify that the absorption resonance stems from optical transitions of the Wigner-induced exciton band structure, rather than being an accidental occurrence, one can tune the electron density in the semiconductor to control the energy gap $E_{E_1} - E_{A_1}$. The solid lines in Fig. 2(a) show the energy shifts of these states in a triangular Wigner lattice. The energy gaps between E_1 (black solid line) and any of the A_1 states (red or blue solid lines) increase with electron density.

Figure 2(a) shows that the energy shift of the trion (X^{-}) has the smallest change when the electron density increases. As long as $w \sim r_x \ll r_s$, the strong localization around the lattice sites renders the trion state less susceptible to a change in electron density [Figs. 1(e) and 1(f)]. The slight redshift of the trion energy when the density increases is explained by the slightly improved overlap of the wave function between lattice sites. In sharp contrast, the exciton states are extended, meaning they are susceptible to density changes. Their energy blueshift becomes stronger as the exciton becomes more extended (i.e., higher energy), as can be seen by comparing the smaller blueshift of $A_1(X^0)$ compared with that of E_1 in Fig. 2(a). The reason is that the attractive potential from lattice sites tends to lower the energy of the state, and higher-energy states better avoid these sites, as can be seen in Figs. 1(e) and 1(f).

To further understand the energy blueshift of extended states, we repeat the calculation by turning off the potential, $V_0 \rightarrow 0$. The band structure in this nearly-free-exciton model is shown in Fig. 2(b). While trion states evolve from the lowest-energy band around the Γ point, exciton states evolve from the excited energy bands around the Γ point. The sixfold state degeneracy of the second state originates from the six Γ points at the centers of the second Brillouin zones, highlighted by green hexagons in Fig. 1(b). The energy of this degenerate state is linearly related to electron density in the nearly-free-exciton model

$$E_{\Gamma}^{\triangle} = \frac{\hbar^2}{M} \frac{4\pi^2}{\sqrt{3}} n,\tag{5}$$

shown by the dashed line in Fig. 2(a). When $V_0 \neq 0$, the excitonlike states $A_1(X^0)$ and E_1 are not completely free, since the lattice potential lowers their energy from that of the nearly free model. Yet, the linear dependence on charge density is largely kept, especially for higher-energy states as shown in Fig. 2(a). The relatively strong energy shift of the exciton compared with that of the trion comes from the difficulty of the exciton state to remain extended when the electron density increases (i.e., smaller distance between lattice sites).

The behavior shown in Fig. 2(a) is corroborated in optical experiments of electrostatically doped TMD monolayers in which the electrons (or holes) are not necessary

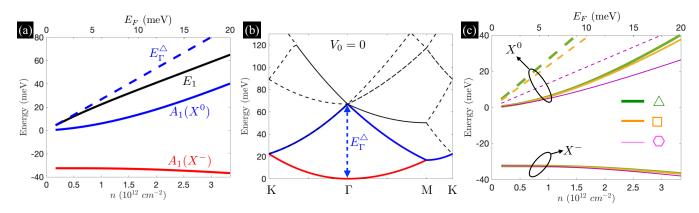


FIG. 2. (a) Γ -point energies of the trion (X^-) , bright exciton (X^0) , and excited exciton state with E_1 symmetry as a function of electron density n (bottom x axis) or Fermi energy $E_F = \hbar^2 \pi n/m_e$ (top x axis, where $m_e = 0.4m_0$). The dashed line denotes the energy E_Γ^{\triangle} of the nearly-free-exciton model. (b) Energy band structure of the nearly-free-exciton model $(V_0 = 0)$ when $n = 2.5 \times 10^{12}$ cm⁻². (c) Γ -point energies of the trion and exciton in three lattice structures: triangular (green), square (orange), and honeycomb (magenta). The dashed lines are the respective E_Γ^{\triangle} , E_Γ^{\square} , and E_Γ^{\triangle} of the nearly-free-exciton model.

ordered [29-35]. Regardless of such order, the small energy shift of the trion should persist as long as the average distance between two electrons in the interacting electron gas is large compared with the extension of the trion wave function. Similarly, the energy blueshift of excitons exists even when electrons are not ordered because of the susceptibility of extended states to density changes [36]. The signature of an electron Wigner crystal manifests through enhancement of the energy blueshift. Before analyzing how order affects the energy shifts, we note that the trion and exciton states in our model have similar attributes to attractive and repulsive polarons in the following sense [10,24]. The attractive polaron in our case is an exciton that is strongly attracted to lattice sites, whereas the repulsive polaron is an exciton that tends to stay away from them. Both attributes are seen in Figs. 1(e) and 1(f), where the lattice site is at the center of the unit cell. Contrary to the Fermi-polaron picture, however, our model explains the energy shifts as a natural consequence of the orthogonality between trion and exciton states without resorting to the polarization of the electron gas.

The dependence of the trion and exciton energies on the order of electrons is further explored by repeating the calculations in square and honeycomb 2D lattices. The Supplemental Material provides detailed information of their exciton band structures [42]. Figure 2(c) shows the energy dependence of the trion (X^-) and exciton (X^0) states on electron density in the three studied lattices. The dashed lines correspond to Γ -point energy gaps in the nearly-free-exciton model of each lattice type,

$$E_{\Gamma}^{\square} = \frac{\hbar^2}{M} 2\pi^2 n$$
 and $E_{\Gamma}^{\bigcirc} = \frac{1}{2} E_{\Gamma}^{\triangle} = \frac{\hbar^2}{M} \frac{2\pi^2}{\sqrt{3}} n$. (6)

Figure 2(c) shows that the trion energy weakly depends on the lattice type, whereas the exciton energy shows clear dependence. The reason is that delocalized exciton states can better "sense" the lattice structure at a larger range from the lattice site. To understand the dependence on lattice types, we write the smallest distance between two neighboring electrons in each lattice: $r_s^{\triangle} \simeq 1.07 n^{-1/2}$, $r_s^{\Box} = n^{-1/2}$, and $r_s^{\bigcirc} \simeq$

 $0.877n^{-1/2}$. This parameter is a measure of how close the electrons are packed, indicating that for a certain change in electron density, the resulting change in r_s is largest in the triangular lattice. As such, the energy blueshift of the exciton in this lattice has the strongest dependence on density.

The dependence of the exciton energy blueshift on the lattice type is a central result of this Letter. It suggests that the blueshift is stronger when the lattice tends to structures with higher symmetry. Such a change in energy blueshift of the exciton can be used as a precursor to Wigner crystallization [12]. For example, the energy blueshift becomes weaker when the temperature increases due to the reduced order of the lattice [36]. The Wigner crystal should also become disordered by continuing to increase the electron density (when r_s is small enough) [46,47]. The broadening of the exciton peak when the charge density increases or at elevated temperatures can be modeled by spatial fluctuations of r_s . Finally, we mention that regardless of order, the energy blueshift effect is relatively strong when the electron of the exciton has different quantum numbers than those of the semiconductor electrons (spin and/or valley) [36]. Otherwise, Pauli exclusion helps the exciton to avoid indistinguishable electrons [6,48], leading to a weaker energy blueshift due to the exchange interaction.

In conclusion, we have presented a band theory to study the behavior of excitons and trion states in electrostatically doped semiconductors. We have explained how energies of these states shift as a function of electron density, and provided important guidelines to detect the elusive Wigner crystal if the electrons of the host semiconductor are ordered. Ramifications of this study can be used to emulate various lattices in which excitons propagate in the same manner that electrons propagate in atomic crystals or light in photonic crystals. Beyond Wigner crystals, such lattices can emerge in moiré heterostructures [49,50] or atom-decorated monolayer semiconductors. In the latter case, advanced fabrication techniques can engineer artificial lattices with various symmetries through controlled placement of atoms or molecules in or adjacent to 2D semiconductors. Such fabricated lattices can be used as far-infrared light detectors, as a means to enhance the functionality of polariton cavities, or as a platform to further investigate excitonic band structures.

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